MIL-PRF-38534 CERTIFIED

RAD TOLERANT, HIGH SPEED, BUFFER AMPLIFIER

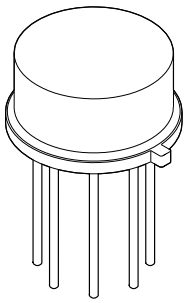
0002RH

M.S.KENNEDY CORP.

4707 Dey Road Liverpool, N.Y. 13088 (315) 701-6751

FEATURES:

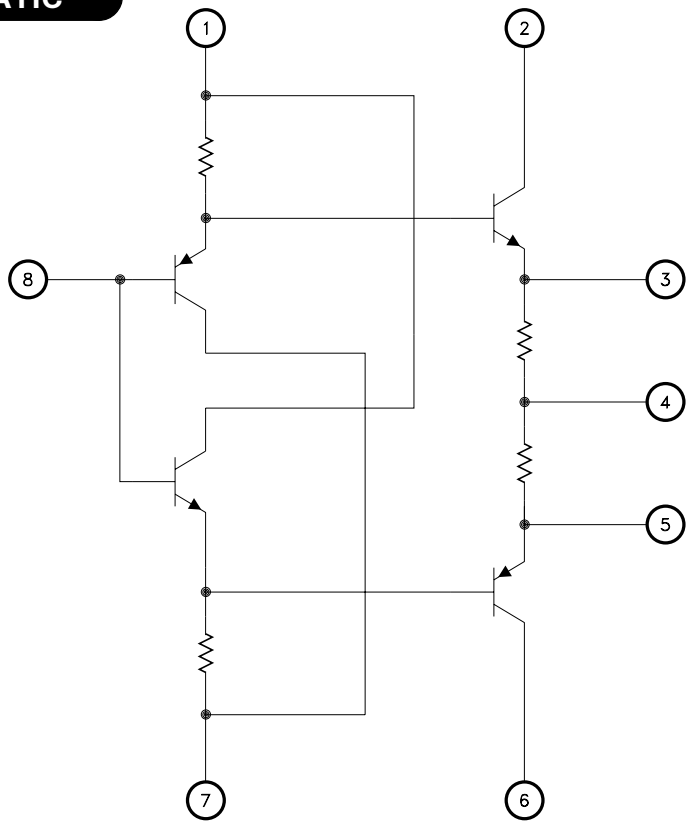
- Total Dose Tested to 300 Krads (Si)
- RAD Tolerant LH0002 Replacement
- High Input Impedance-180KΩ Min
- Low Output Impedance-10Ω Max
- Low Harmonic Distortion
- DC to 30 MHz Bandwidth
- Slew Rate is Typically 400 V/μS
- Operating Range from ±5V to ±20V
- Contact MSK for MIL-PRF-38534 Qualification Status and Appendix G (Radiation Status)



DESCRIPTION:

The MSK 0002RH is a general purpose current amplifier. It is the industry wide RAD tolerant replacement for the LH0002. The device is ideal for use with an operational amplifier in a closed loop configuration to increase current output. The MSK 0002RH is designed with a symmetrical output stage that provides low output impedances to both the positive and negative portions of output pulses. The MSK 0002RH is packaged in a hermetic 8 lead low profile T0-5 header and is specified over the full military temperature range.

EQUIVALENT SCHEMATIC



TYPICAL APPLICATIONS

- High Speed D/A Conversion
- 30MHz Buffer
- Line Driver
- Precision Current Source

PIN-OUT INFORMATION

1	V1+	5	E4
2	V2+	6	V2-
3	E3	7	V1-
4	Output	8	Input

ABSOLUTE MAXIMUM RATINGS ⑤

±V_{CC}	Supply Voltage . . . . . ±20V	T_{ST}	Storage Temperature Range -65°C to +150°C
V_{IN}	Input Voltage . . . . . ±20V	T_{LD}	Lead Temperature Range . . . . . +300°C
P_d	Power Dissipation 600mW		(10 Seconds)
Tc	Case Operating Temperature	T_J	Junction Temperature . . . . . +175°C
	(MSK 0002K/H/E RH) . . . . . -55°C to +125°C	θ_{jC}	Thermal Resistance @ TC = 125°C
	(MSK 0002RH) . . . . . -40°C to +85°C		Output Devices . . . . . 55°C/W

ELECTRICAL SPECIFICATIONS

Parameter	Test Conditions ①⑥	Group A Subgroup	MSK 0002K/H/E RH ④			MSK 0002RH			Units
			Min.	Typ.	Max.	Min.	Typ.	Max.	
Quiescent Current	V_{IN} = 0V R_S = 10KΩ R_L = 1.0KΩ	1	-	±6.3	±10	-	±6.3	±12	mA
Input Current	R_S = 10KΩ R_L = 1.0KΩ	1	-	±5	±15	-	±5	±20	µA
		2,3	-	±10	±20	-	-	-	µA
Output Offset Voltage	R_S = 300Ω R_L = 1.0KΩ	1	-	±6	±30	-	±6	±35	mV
		2,3	-	±10	±30	-	-	-	mV
Input Impedance ③	V_{IN} = 1.0V_{RMS} R_S = 200KΩ R_L = 1KΩ f = 1.0KHz	4	180	-	-	180	-	-	KΩ
Output Impedance ③	V_{IN} = 1.0V_{RMS} R_S = 10KΩ R_L = 50Ω f = 1.0KHz	4	-	-	10	-	-	10	Ω
Output Voltage Swing	R_L = 1.0KΩ f = 1.0KHz	4	±10	±11	-	±10	±11	-	Vp
	R_L = 100Ω ±V_{CC} = ±15V f = 1.0KHz	4	±9.5	-	-	±9.5	-	-	Vp
Voltage Gain ②	V_{IN} = 3.0V_{PP} f = 1.0KHz	4	0.95	0.97	-	0.95	0.97	-	V/V
	R_S = 10KΩ R_L = 1.0KΩ	5,6	0.92	-	-	-	-	-	V/V
Rise Time	V_{OUT} = 2.5V_{PP} f = 10KHz R_S = 100Ω R_L = 50Ω	4	-	6	12	-	6	15	nS

NOTES:

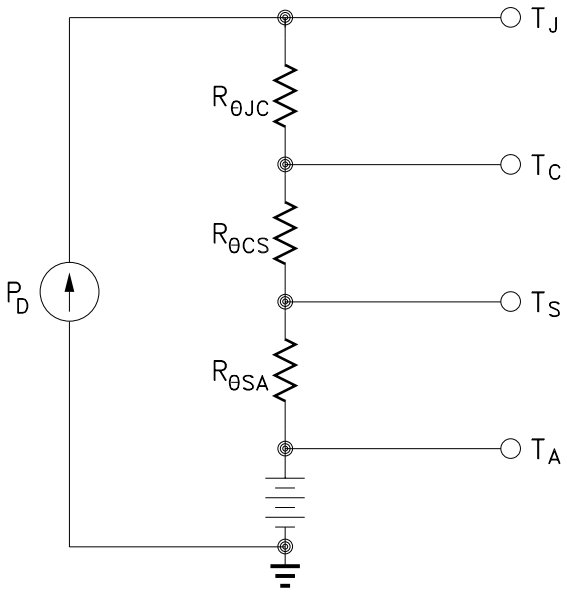
① Unless otherwise specified ±V_{CC} = ±12V_{DC}, R_L = 1KΩ.
② Subgroups 5 & 6 shall be tested as part of device initial characterization and after design and process changes. Parameter shall be guaranteed to the limits specified for subgroups 5 & 6 for all lots not specifically tested.
③ Devices shall be capable of meeting the parameter, but need not be tested.
④ Subgroup 1,4 T_A = T_C = +25°C
Subgroup 2,5 T_A = T_C = +125°C
Subgroup 3,6 T_A = T_C = -55°C
⑤ Continuous operation at or above absolute maximum ratings may adversly effect the device performance and/or life cycle.
⑥ Consult factory for post radiation limits.

APPLICATION NOTES

HEAT SINKING

To determine if a heat sink is necessary for your application and if so, what type, refer to the thermal model and governing equation below.

Thermal Model:



Governing Equation:

$T_J = P_D \times (R_{\theta JC} + R_{\theta CS} + R_{\theta SA}) + T_A$

Where

T_J = Junction Temperature
P_D = Total Power Dissipation
$R_{\theta JC}$ = Junction to Case Thermal Resistance
$R_{\theta CS}$ = Heat Sink to Ambient Thermal Resistance
T_C = Case Temperature
T_A = Ambient Temperature
T_S = Sink Temperature

Example:

This example demonstrates a worst case analysis for the buffer output stage. This occurs when the output voltage is 1/2 the power supply voltage. Under this condition, maximum power transfer occurs and the output is under maximum stress.

Conditions:

VCC = ±12VDC
Vo = ±6Vp Sine Wave, Freq. = 1KHz
RL = 100Ω

For a worst case analysis we will treat the ±6Vp sine wave as an 6 VDC output voltage.

1.) Find Driver Power Dissipation
PD = (Vcc-Vo) (Vo/RL)
= (12V-6V) (6V/100Ω)
= 360mW
2.) For conservative design, set T_J = +125°C Max.
3.) For this example, worst case T_A = +80°C
4.) $R_{\theta JC}$ = 55° C/W from MSK 0002RH Data Sheet
5.) $R_{\theta CS}$ = 0.15° C/W for most thermal greases
6.) Rearrange governing equation to solve for $R_{\theta SA}$

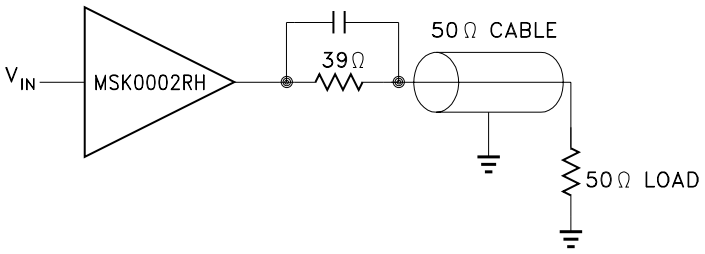
$R_{\theta SA} = ((T_J - T_A)/P_D) - (R_{\theta JC}) - (R_{\theta CS})$
$= ((125°C - 80°C) / 0.36W) - 55°C/W - 0.15°C/W$
$= 125 - 55.15$
$= 69.9°C/W$

This heat sink in this example must have a thermal resistance of no more than 69.9°C/W to maintain a junction temperature of no more than +125°C.

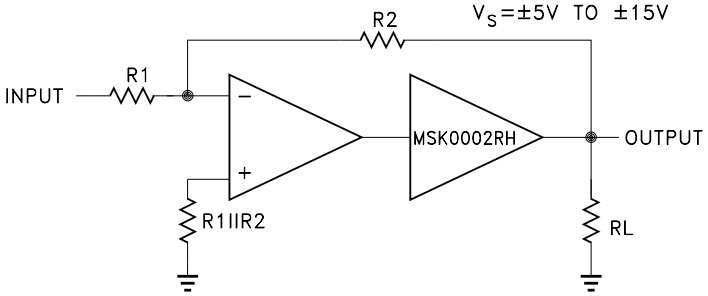
Typical Applications:

LINE DRIVER

SELECT CAPACITOR TO ADJUST TIME RESPONSE OF PULSE.



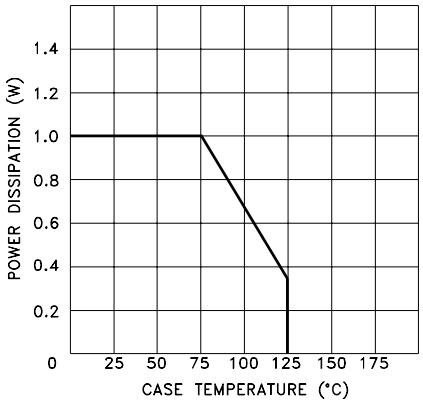
HIGH CURRENT OPERATIONAL AMPLIFIER



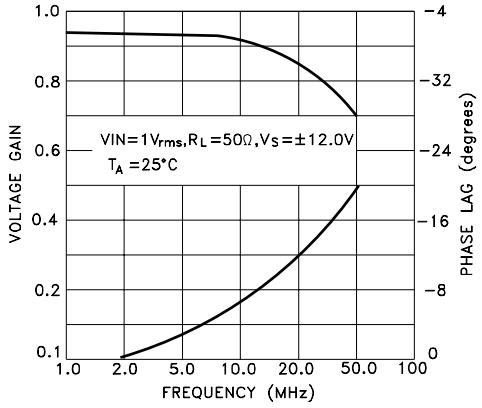
TYPICAL PERFORMANCE CURVES

查询"MSK0002ERH"供应商

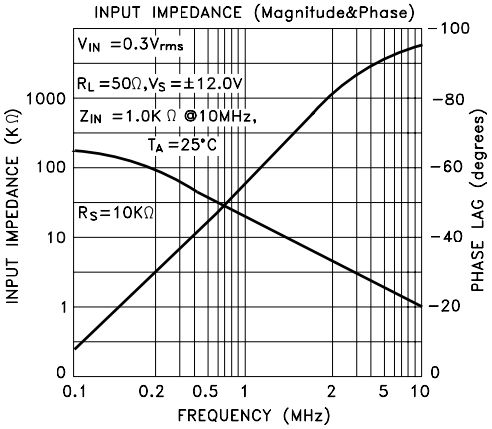
MAXIMUM POWER DISSIPATION



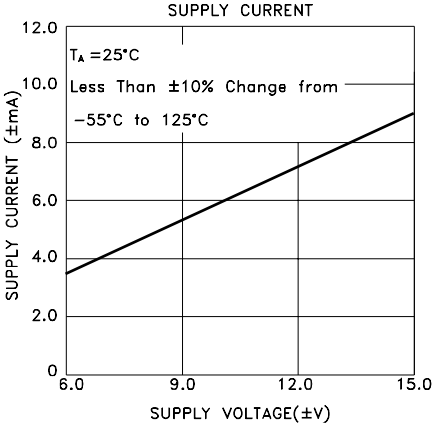
FREQUENCY RESPONSE



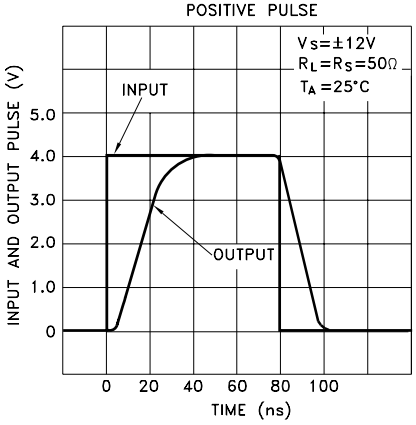
INPUT IMPEDANCE (Magnitude&Phase)



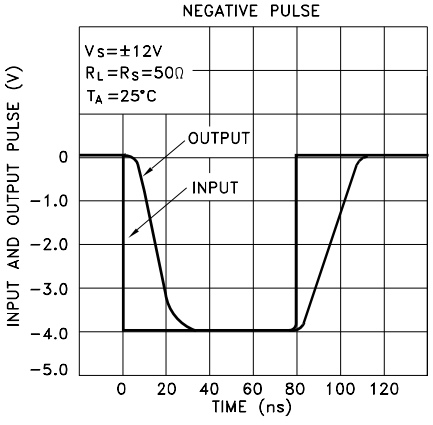
SUPPLY CURRENT



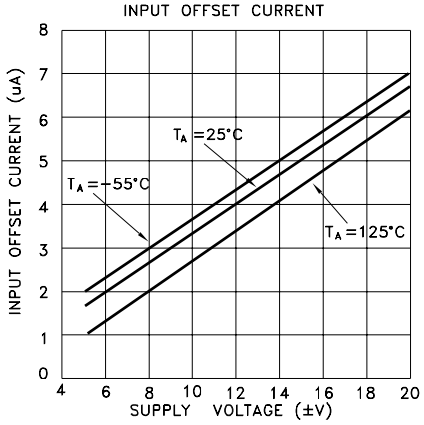
POSITIVE PULSE



NEGATIVE PULSE

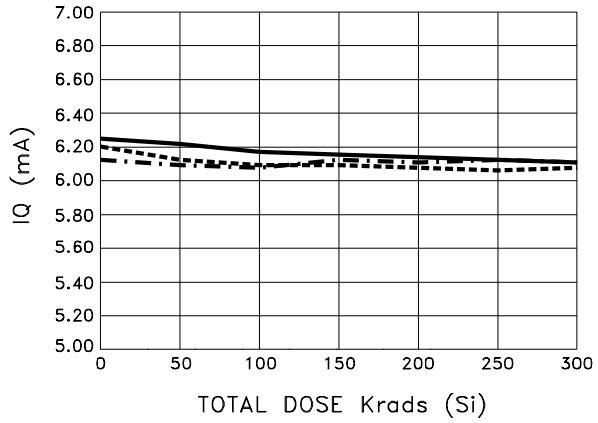


INPUT OFFSET CURRENT

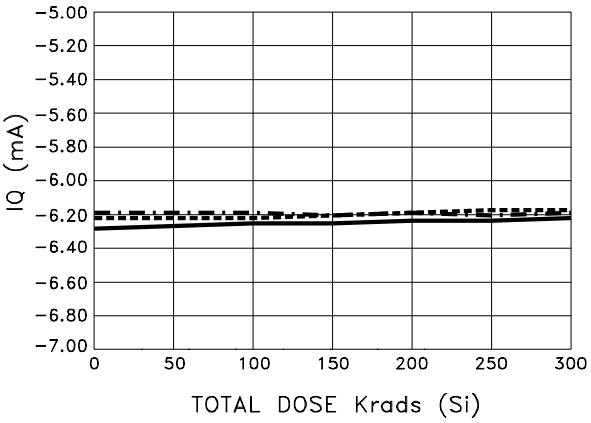


RADIATION CURVES

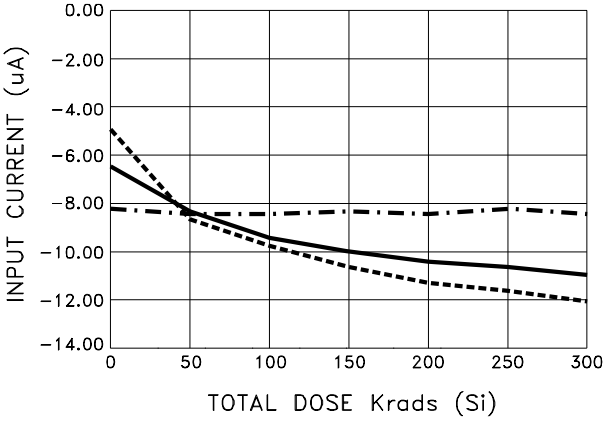
POSITIVE IQ vs TOTAL DOSE



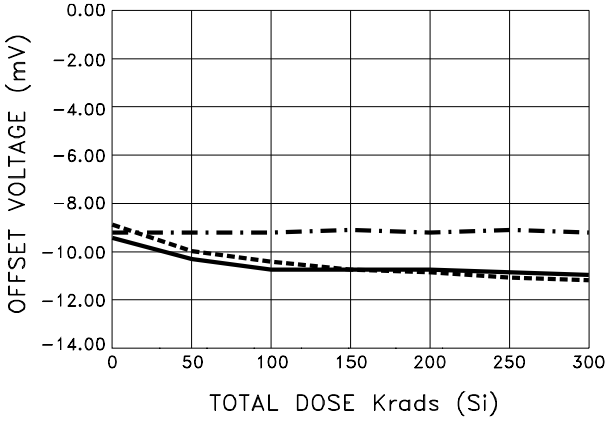
NEGATIVE IQ vs TOTAL DOSE



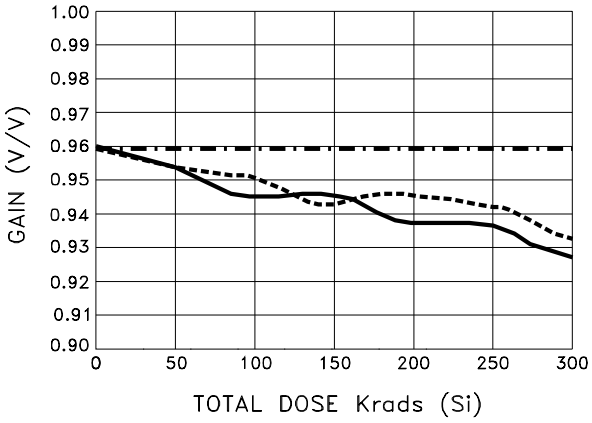
INPUT CURRENT vs TOTAL DOSE

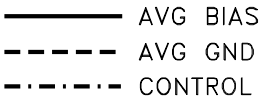


OFFSET VOLTAGE vs TOTAL DOSE



GAIN vs TOTAL DOSE

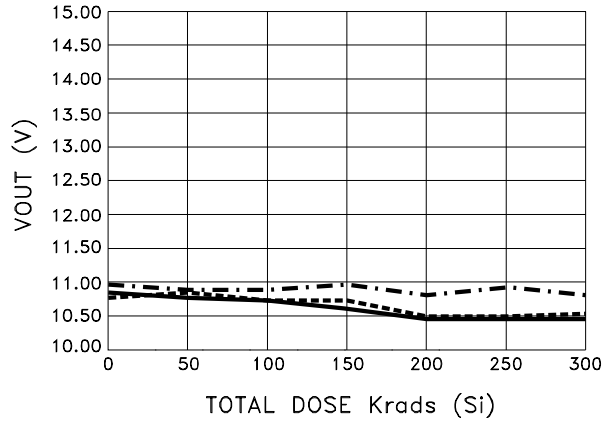




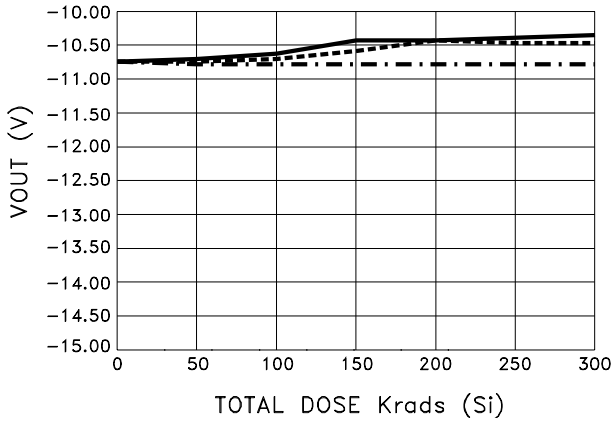
NOTE: All radiation curve test conditions are in accordance with the electrical specifications table (page 2). See RAD report for bias and dose rate.

RADIATION CURVES CONT'D

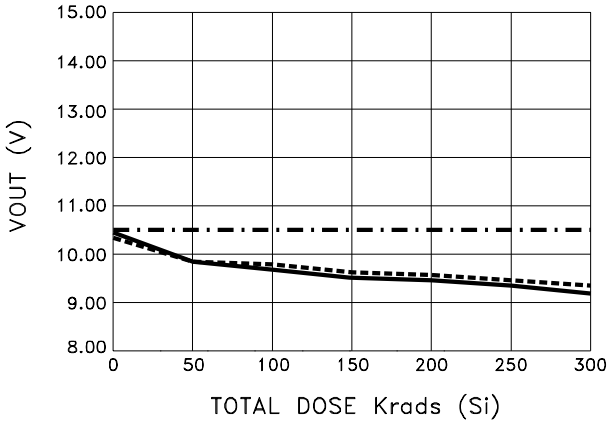
VOUT 1 POSITIVE vs TOTAL DOSE



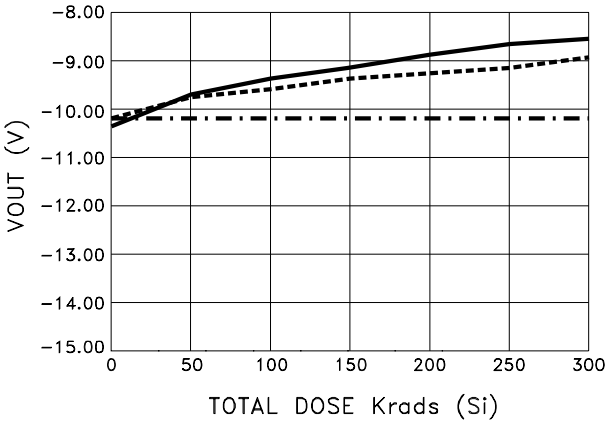
VOUT 1 NEGATIVE vs TOTAL DOSE



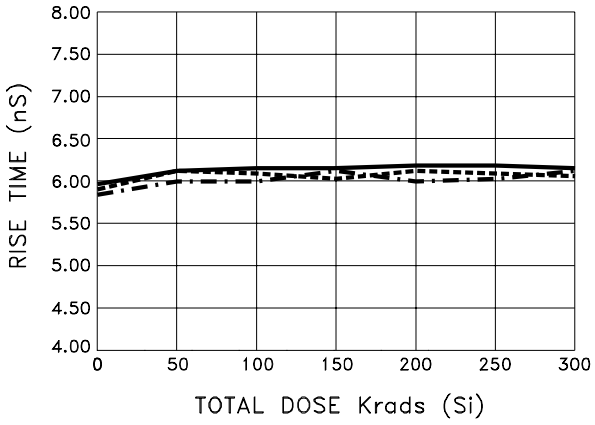
VOUT 2 POSITIVE vs TOTAL DOSE

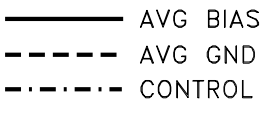


VOUT 2 NEGATIVE vs TOTAL DOSE



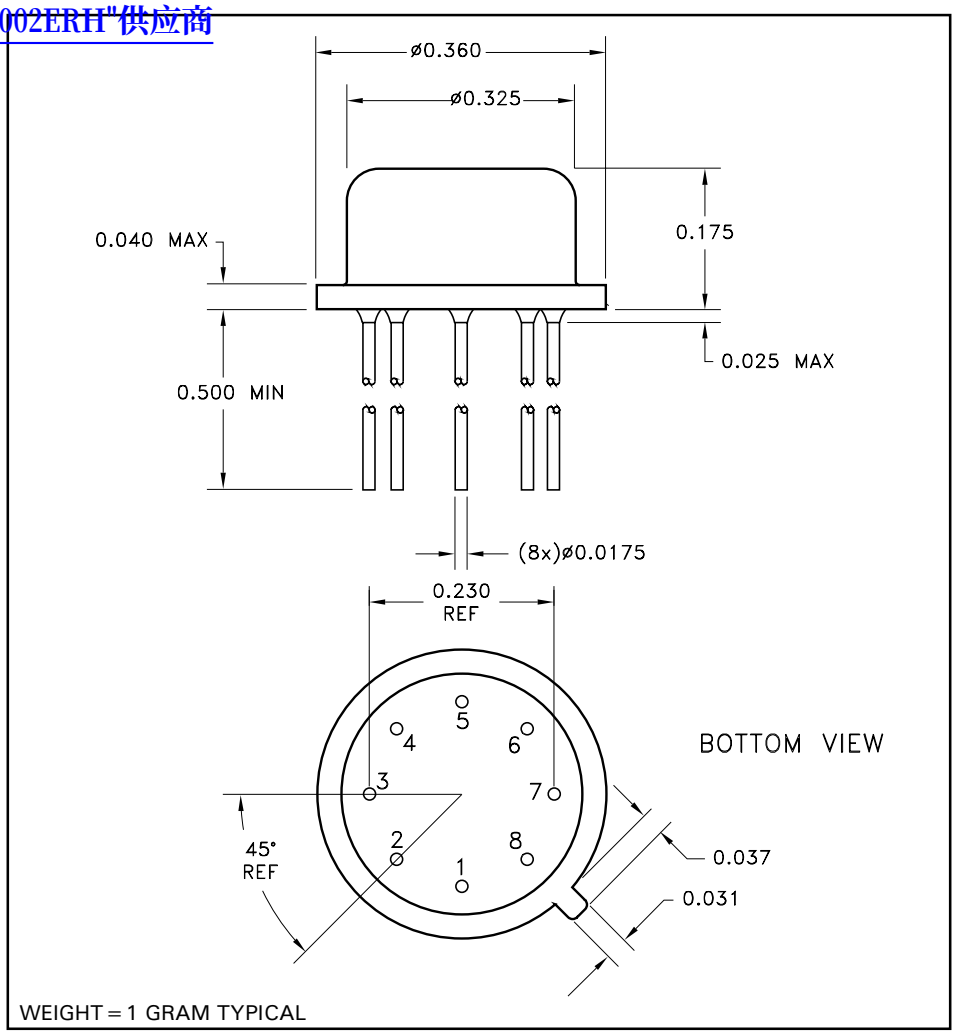
RISE TIME vs TOTAL DOSE





NOTE: All radiation curve test conditions are in accordance with the electrical specifications table (page 2). See RAD report for bias and dose rate.

MECHANICAL SPECIFICATIONS



ALL DIMENSIONS ARE ±0.010 INCHES UNLESS OTHERWISE LABELED

ORDERING INFORMATION

Part Number	Screening Level
MSK0002RH	Industrial
MSK0002ERH	Extended Reliability
MSK0002HRH	MIL-PRF-38534 Class H
MSK0002KRH	MIL-PRF-38534 Class K

M.S. Kennedy Corp.
4707 Dey Road, Liverpool, New York 13088
Phone (315) 701-6751
FAX (315) 701-6752
www.mskennedy.com